

	<h2 style="color: orange;">FQB10N20CTM</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: FQB10N20CTM
	Hersteller / Marke: Fairchild/ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 200V 9.5A D2PAK
	Datenblätter:  FQB10N20CTM.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 37163 pcs Stock Available.
	Liefern von: Hong Kong
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FQB10N20CTM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 200V 9.5A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	37163 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	72W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (V _{dss})	200V
Strom - Ununterbrochener Abfluss (I _d) bei 25 ° C	9.5A (Tc)
R _{ds On} (Max) @ I _d , V _{gs}	360 mOhm @ 4.75A, 10V
V _{GS} (th) (Max) @ I _d	4V @ 250µA
Gate Charge (Q _g) (Max) @ V _{gs}	26nC @ 10V
Eingabekapazität (C _{iss}) (Max) @ V _{ds}	510pF @ 25V
Verpackung	Tape & Reel (TR)



















































FQB10N20CTM ist neu im Original, Suche FQB10N20CTM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB10N20CTM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB10N20CTM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB10N20TM Fairchild/ON Semiconductor MOSFET N-CH 200V 10A D2PAK</p>	 <p>FQB10N20TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 10A D2PAK</p>	 <p>FQB10N20L FAIRCHILD FQB10N20L FAIRCHILD</p>	 <p>FQB10N20CTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 9.5A D2PAK</p>
 <p>FQB10N20LTM Fairchild/ON Semiconductor MOSFET N-CH 200V 10A D2PAK</p>	 <p>FQB10N20LTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 10A D2PAK</p>	 <p>FQB10N50CFTM FSC FQB10N50CFTM FSC</p>	 <p>FQB060AN08AO FAIRCHILD FAIRCHILD TO-263</p>

heiße Teile

Mehr

 FQB10N20C	 FQB10N20CTM	 FQB10N20L	 FQB10N20LTM	 FQB10N20LTM
 FQB10N20TM	 FQB10N20TM	 FQB10N50CF	 FQB10N50CFTM	 FQB10N50CFTM_WS
 FQB10N60C	 FQB10N60CTM	 FQB10N60CTM	 FQB11N40	 FQB11N40C
 FQB11N40CTM	 FQB11N40CTM	 FQB11N60FTM	 FQB11N60TM	 FQB11P06
 FQB11P06TM	 FQB11P06TM	 FQB11P06TM**CN-SCI	 FQB12N50TM	 FQB12N50TM_AM002
 FQB12N50TM_AM002	 FQB12N60	 FQB12N60C	 FQB12N60CTM	 FQB12N60CTM
 FQB12N60TM	 FQB12N60TM_AM002	 FQB12N60TM_AM002	 FQB12P10	 FQB12P10TM
 FQB12P10TM	 FQB12P20	 FQB12P20TM	 FQB12P20TM	 FQB13N06L
 FQB13N10	 FQB13N10L	 FQB13N50	 FQB13N50CTM	 FQB13N50CTM
 FQB140N03L	 FQB14N30TM	 FQB14N30TM	 FQB16N25TM	 FQB16N25TM

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